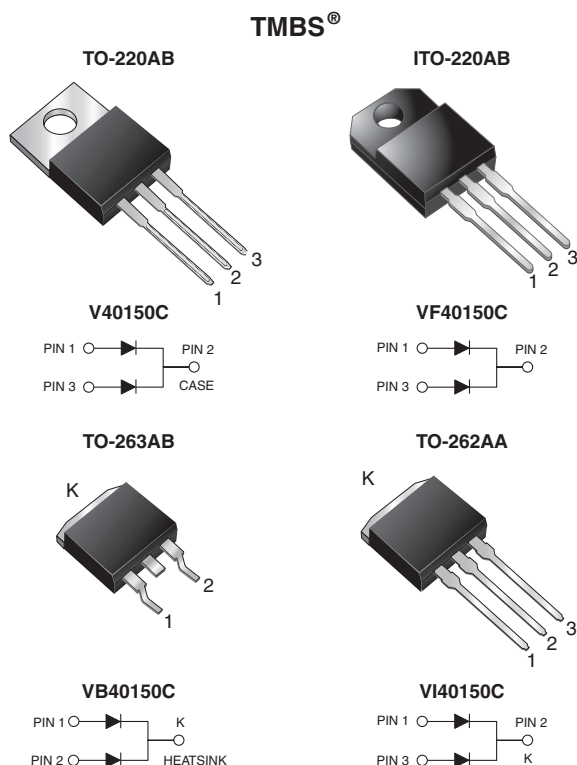


Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.55 \text{ V}$ at $I_F = 5 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 20 A
V_{RRM}	150 V
I_{FSM}	160 A
V_F at $I_F = 20 \text{ A}$	0.75 V
T_J max.	150 °C
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT
Max. repetitive peak reverse voltage	V _{RRM}	150				V
Max. average forward rectified current (fig. 1)	per device I _{F(AV)}	40				A
	per diode I _{F(AV)}	20				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	160				A
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode	E _{AS}	150				mJ
Peak repetitive reverse current at t _p = 2 μs, 1 kHz, T _J = 38 °C ± 2 °C per diode	I _{RRM}	0.5				A
Voltage rate of change (rated V _R)	dV/dt	10 000				V/μs
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150				°C

**ELECTRICAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	TYP	MAX.	UNIT
Breakdown voltage	$I_R = 1.0\text{ mA}$ $T_A = 25\text{ }^{\circ}\text{C}$	V_{BR}	150 (min.)	-	V
Instantaneous forward voltage per diode ⁽¹⁾	$I_F = 5\text{ A}$ $T_A = 25\text{ }^{\circ}\text{C}$	V_F	0.69	-	V
	$I_F = 10\text{ A}$		0.84	-	
	$I_F = 20\text{ A}$		1.15	1.43	
	$I_F = 5\text{ A}$ $T_A = 125\text{ }^{\circ}\text{C}$		0.55	-	
	$I_F = 10\text{ A}$		0.64	-	
	$I_F = 20\text{ A}$		0.75	0.82	
Reverse current per diode ⁽²⁾	$V_R = 100\text{ V}$ $T_A = 25\text{ }^{\circ}\text{C}$	I_R	2	-	μA
	$V_R = 100\text{ V}$ $T_A = 125\text{ }^{\circ}\text{C}$		2.5	-	mA
	$V_R = 150\text{ V}$ $T_A = 25\text{ }^{\circ}\text{C}$		-	250	μA
	$V_R = 150\text{ V}$ $T_A = 125\text{ }^{\circ}\text{C}$		5	25	mA

Notes⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle⁽²⁾ Pulse test: Pulse width $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40150C	VF40150C	VB40150C	VI40150C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	1.8	4	1.8	1.8	$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V40150C-E3/4W	1.89	4W	50/tube	Tube
ITO-220AB	VF40150C-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VB40150C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40150C-E3/8W	1.39	8W	800/reel	Tape and reel
TO-262AA	VI40150C-E3/4W	1.46	4W	50/tube	Tube

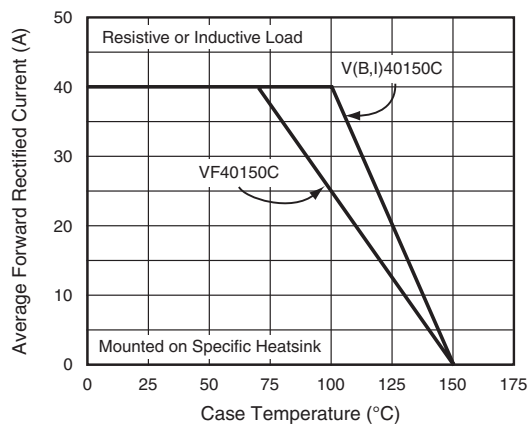
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

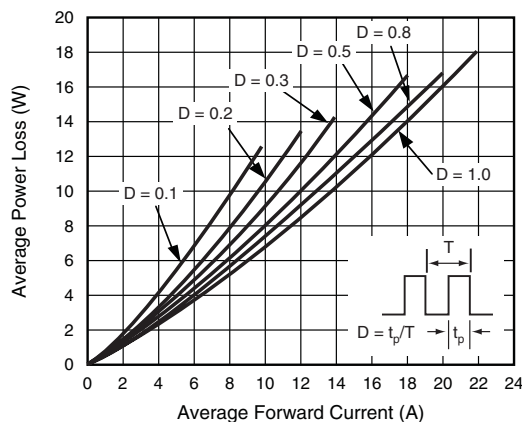


Fig. 2 - Forward Power Loss Characteristics Per Diode

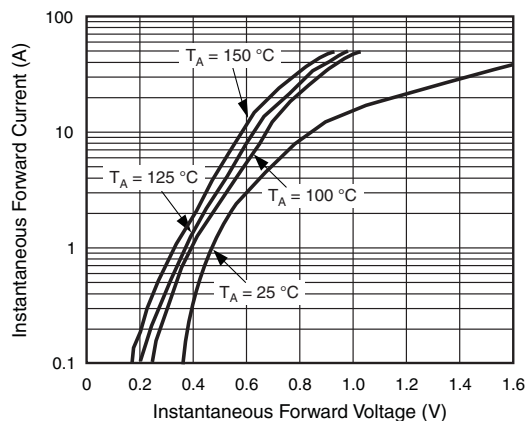


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

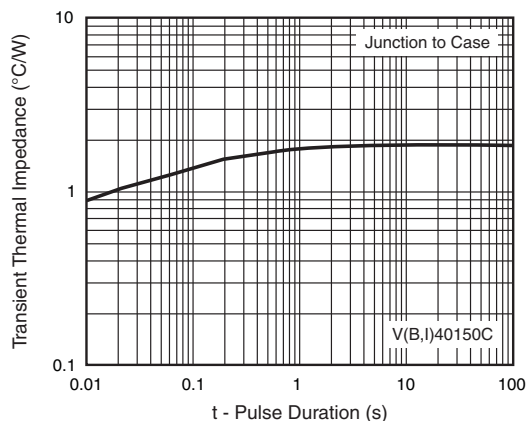


Fig. 6 - Typical Transient Thermal Impedance Per Diode

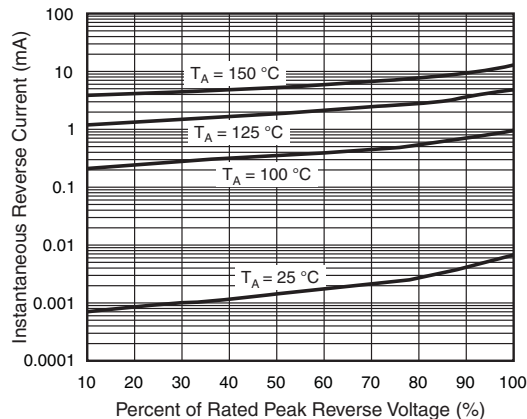


Fig. 4 - Typical Reverse Characteristics Per Diode

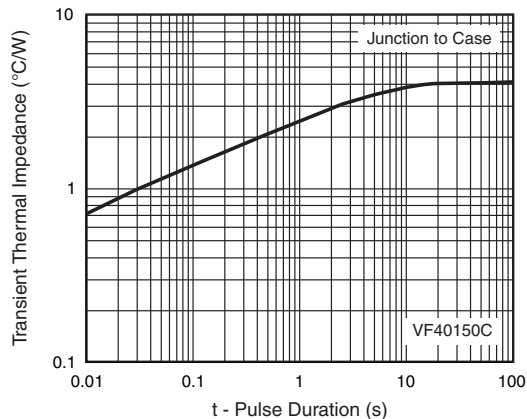


Fig. 7 - Typical Transient Thermal Impedance Per Diode

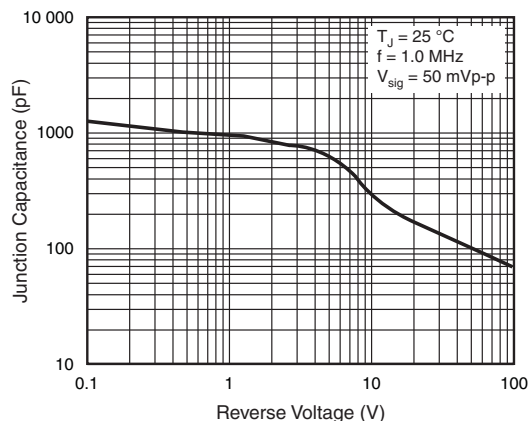
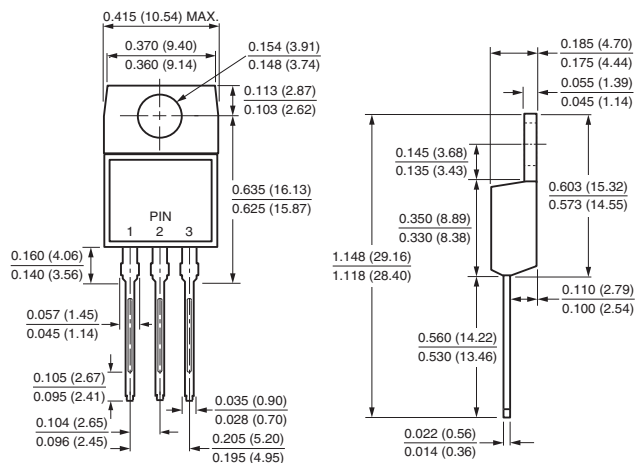


Fig. 5 - Typical Junction Capacitance

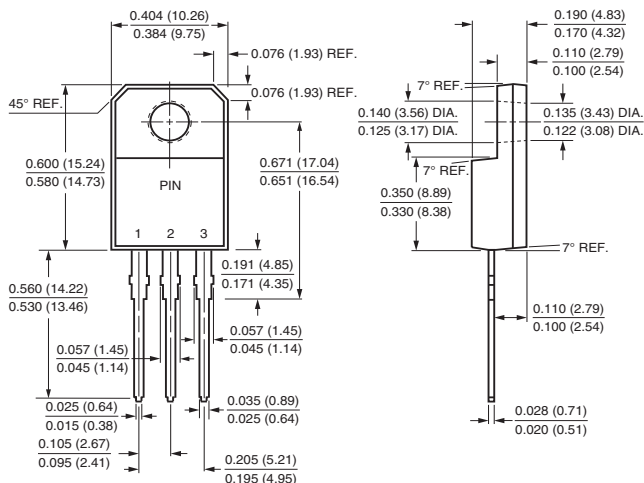


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

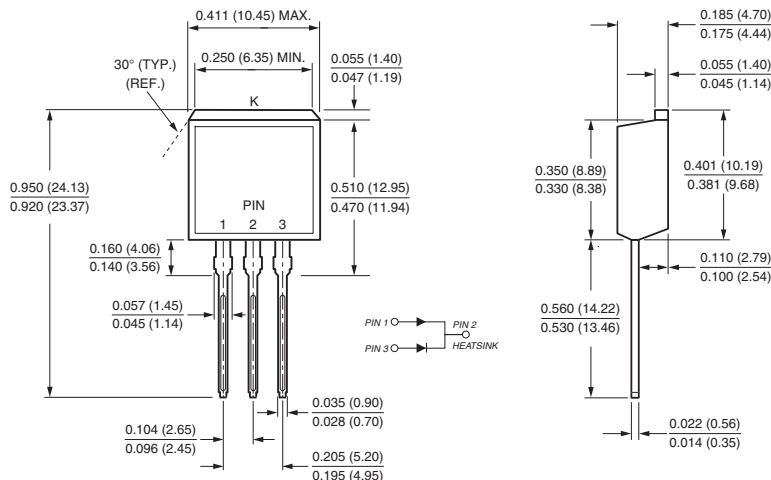
TO-220AB



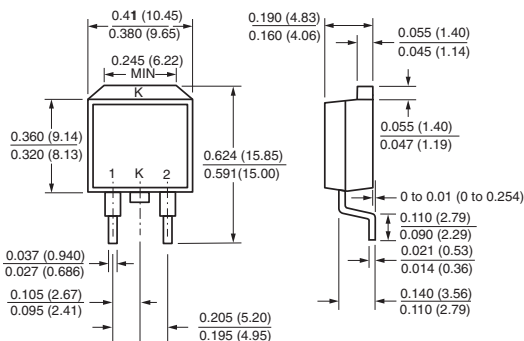
ITO-220AB



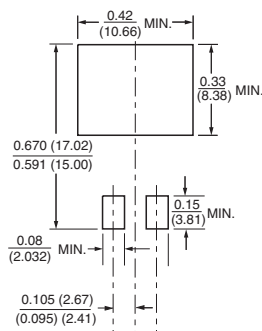
TO-262AA



TO-263AB



Mounting Pad Layout





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